NSN 5961-00-478-2925

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-478-2925
Inclosure Material:
Plastic
Overall Length:
0.385 inches
Overall Height:
0.185 inches
Overall Width:
0.360 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
29.0 breakover voltage, dc
Current Rating Per Characteristic:
10.00 amperes source cutoff current of standard range
Power Rating Per Characteristic:
$600.0 \ milliwatts$ small-signal input power, $\ common\mbox{-collector}$ preset
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0